

TC74AC00P

1. Functional Description

- Quad 2-Input NAND Gate

2. General

The TC74AC00P is an advanced high speed CMOS 2-INPUT NAND GATE fabricated with silicon gate and double-layer metal wiring C²MOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

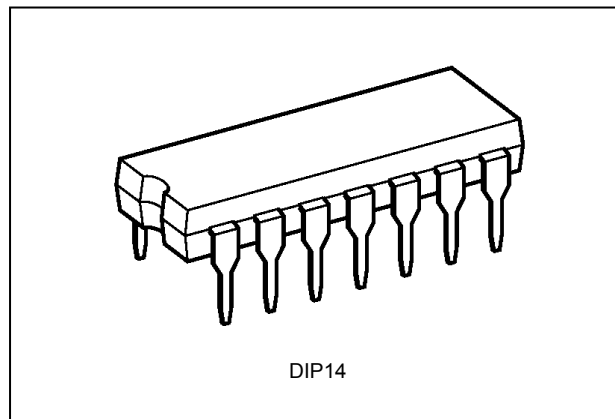
The internal circuit is composed of 3 stages including buffer output, which provide high noise immunity and stable output.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

3. Features

- (1) High speed: $t_{pd} = 3.8 \text{ ns (typ.)}$ $V_{CC} = 5.0 \text{ V}$
- (2) Low power dissipation: $I_{CC} = 4.0 \mu\text{A (max)}$ $T_a = 25 \text{ }^\circ\text{C}$
- (3) High noise immunity: $V_{NIH} = V_{NIL} = 28 \% V_{CC} \text{ (min)}$
- (4) Output current: $|I_{OH}|/I_{OL} = 24 \text{ mA (min)}$ ($V_{CC} = 4.5 \text{ V}$)
- (5) Balanced propagation delays: $t_{PLH} \approx t_{PHL}$
- (6) Wide operating voltage range: $V_{CC(opr)} = 2.0 \text{ V to } 5.5 \text{ V}$
- (7) Pin and function compatible with 74F00.

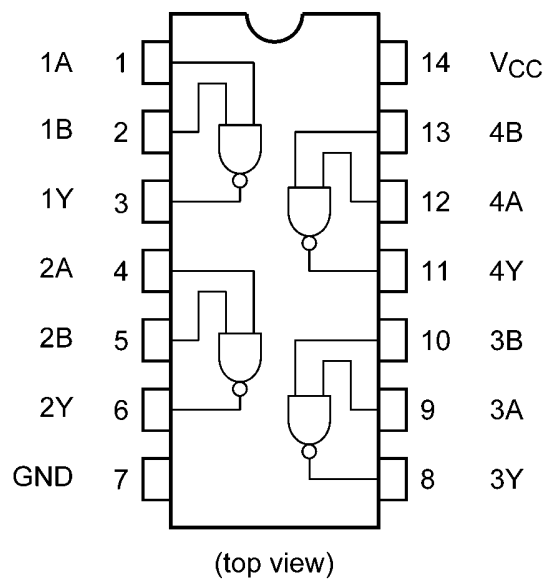
4. Packaging



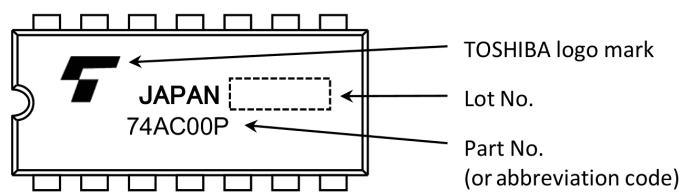
Start of commercial production

1986-05

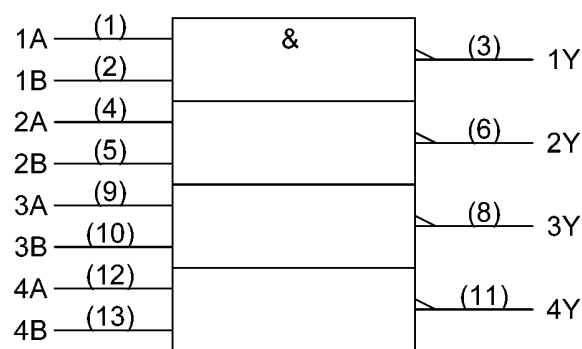
5. Pin Assignment



6. Marking



7. IEC Logic Symbol



8. Truth Table

A	B	Y
L	L	H
L	H	H
H	L	H
H	H	L

9. Absolute Maximum Ratings (Note)

Characteristics	Symbol	Note	Rating	Unit
Supply voltage	V_{CC}		-0.5 to 7.0	V
Input voltage	V_{IN}		-0.5 to $V_{CC} + 0.5$	V
Output voltage	V_{OUT}		-0.5 to $V_{CC} + 0.5$	V
Input diode current	I_{IK}		± 20	mA
Output diode current	I_{OK}		± 50	mA
Output current	I_{OUT}		± 50	mA
V_{CC} /ground current	I_{CC}		± 100	mA
Power dissipation	P_D	(Note 1)	500	mW
Storage temperature	T_{stg}		-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: 500 mW in the range of $T_a = -40$ to 65°C . From $T_a = 65$ to 85°C a derating factor of -10 mW/°C shall be applied until 300 mW.

10. Operating Ranges (Note)

Characteristics	Symbol		Rating	Unit
Supply voltage	V_{CC}		2.0 to 5.5	V
Input voltage	V_{IN}		0 to V_{CC}	V
Output voltage	V_{OUT}		0 to V_{CC}	V
Operating temperature	T_{opr}		-40 to 85	°C
Input rise and fall times	dt/dv	$V_{CC} = 3.3 \pm 0.3 \text{ V}$	0 to 100	ns/V
		$V_{CC} = 5.0 \pm 0.5 \text{ V}$	0 to 20	

Note: The operating ranges must be maintained to ensure the normal operation of the device.
Unused inputs must be tied to either V_{CC} or GND.

11. Electrical Characteristics

11.1. DC Characteristics (Unless otherwise specified, $T_a = 25\text{ }^{\circ}\text{C}$)

Characteristics	Symbol	Test Condition		V_{CC} (V)	Min	Typ.	Max	Unit
High-level input voltage	V_{IH}	—		2.0	1.50	—	—	V
				3.0	2.10	—	—	
				5.5	3.85	—	—	
Low-level input voltage	V_{IL}	—		2.0	—	—	0.50	V
				3.0	—	—	0.90	
				5.5	—	—	1.65	
High-level output voltage	V_{OH}	$V_{IN} = V_{IH}$ or V_{IL}	$I_{OH} = -50\text{ }\mu\text{A}$	2.0	1.9	2.0	—	V
				3.0	2.9	3.0	—	
				4.5	4.4	4.5	—	
			$I_{OH} = -4\text{ mA}$	3.0	2.58	—	—	
			$I_{OH} = -24\text{ mA}$	4.5	3.94	—	—	
Low-level output voltage	V_{OL}	$V_{IN} = V_{IH}$	$I_{OL} = 50\text{ }\mu\text{A}$	2.0	—	0.0	0.1	V
				3.0	—	0.0	0.1	
				4.5	—	0.0	0.1	
			$I_{OL} = 12\text{ mA}$	3.0	—	—	0.36	
			$I_{OL} = 24\text{ mA}$	4.5	—	—	0.36	
Input leakage current	I_{IN}	$V_{IN} = V_{CC}$ or GND		5.5	—	—	± 0.1	μA
Quiescent supply current	I_{CC}	$V_{IN} = V_{CC}$ or GND		5.5	—	—	4.0	μA

11.2. DC Characteristics (Unless otherwise specified, $T_a = -40\text{ to }85\text{ }^{\circ}\text{C}$)

Characteristics	Symbol	Test Condition		Note	V_{CC} (V)	Min	Max	Unit
High-level input voltage	V_{IH}	—			2.0	1.50	—	V
					3.0	2.10	—	
					5.5	3.85	—	
Low-level input voltage	V_{IL}	—			2.0	—	0.50	V
					3.0	—	0.90	
					5.5	—	1.65	
High-level output voltage	V_{OH}	$V_{IN} = V_{IH}$ or V_{IL}	$I_{OH} = -50\text{ }\mu\text{A}$		2.0	1.9	—	V
					3.0	2.9	—	
					4.5	4.4	—	
			$I_{OH} = -4\text{ mA}$		3.0	2.48	—	
			$I_{OH} = -24\text{ mA}$		4.5	3.80	—	
Low-level output voltage	V_{OL}	$V_{IN} = V_{IH}$	$I_{OL} = 50\text{ }\mu\text{A}$		2.0	—	0.1	V
					3.0	—	0.1	
					4.5	—	0.1	
			$I_{OL} = 12\text{ mA}$		3.0	—	0.44	
			$I_{OL} = 24\text{ mA}$		4.5	—	0.44	
			$I_{OL} = 75\text{ mA}$	(Note 1)	5.5	—	1.65	
Input leakage current	I_{IN}	$V_{IN} = V_{CC}$ or GND			5.5	—	± 1.0	μA
Quiescent supply current	I_{CC}	$V_{IN} = V_{CC}$ or GND			5.5	—	40.0	μA

Note 1: This spec indicates the capability of driving 50 Ω transmission lines.

One output should be tested within a 10 ms maximum duration.

11.3. AC Characteristics (Unless otherwise specified, $T_a = 25\text{ }^{\circ}\text{C}$, Input: $t_r = t_f = 3\text{ ns}$)

Characteristics	Symbol	Note	Test Condition	V_{CC} (V)	Min	Typ.	Max	Unit
Propagation delay time	t_{PLH}, t_{PHL}		$C_L = 50\text{ pF}$ $R_L = 500\text{ }\Omega$	3.3 ± 0.3	—	6.6	11.2	ns
				5.0 ± 0.5	—	4.9	7.0	
Input capacitance	C_{IN}		—	—	5	10		pF
Power dissipation capacitance	C_{PD}	(Note 1)	—	—	68	—		pF

Note 1: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation.

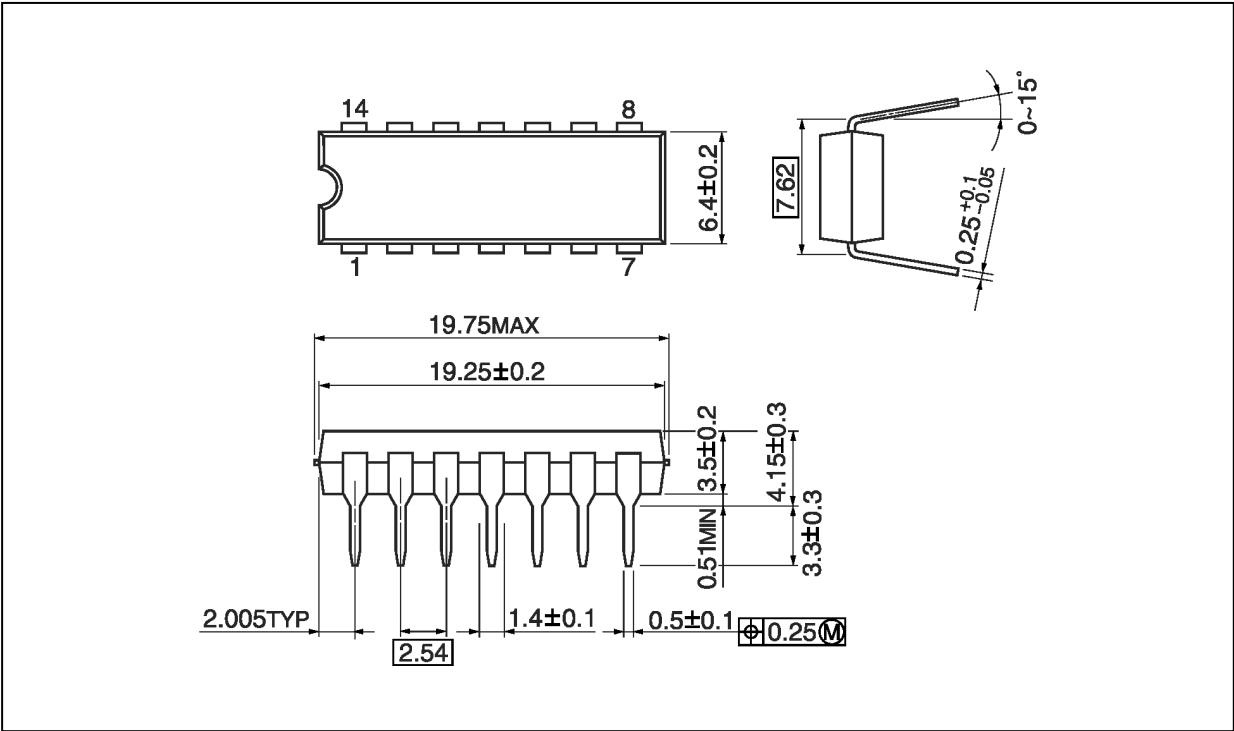
$$I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}/4 \text{ (per gate)}$$

11.4. AC Characteristics (Unless otherwise specified, $T_a = -40\text{ to }85\text{ }^{\circ}\text{C}$, Input: $t_r = t_f = 3\text{ ns}$)

Characteristics	Symbol	Test Condition	V_{CC} (V)	Min	Max	Unit
Propagation delay time	t_{PLH}, t_{PHL}	$C_L = 50\text{ pF}$ $R_L = 500\text{ }\Omega$	3.3 ± 0.3	1.0	12.9	ns
			5.0 ± 0.5	1.0	8.0	
Input capacitance	C_{IN}	—	—	—	10	pF

Package Dimensions

Unit: mm



Weight: 0.96 g (typ.)

Package Name(s)
Nickname: DIP14

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